Endre Tóvári

List of Publications by Year in descending order

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17	505	11	17	
papers	citations	h-index	g-index	
17	17	17	909	
all docs	docs citations	times ranked	citing authors	

#	Article	IF	Citations
1	New method of transport measurements on van der Waals heterostructures under pressure. Journal of Applied Physics, 2021, 130, .	2.5	16
2	In situ tuning of symmetry-breaking-induced nonreciprocity in the giant-Rashba semiconductor BiTeBr. Physical Review Research, 2021, 3, .	3.6	1
3	Boosting proximity spin–orbit coupling in graphene/WSe2 heterostructures via hydrostatic pressure. Npj 2D Materials and Applications, 2021, 5, .	7.9	34
4	Tailoring the Band Structure of Twisted Double Bilayer Graphene with Pressure. Nano Letters, 2021, 21, 8777-8784.	9.1	19
5	Ultra-thin van der Waals crystals as semiconductor quantum wells. Nature Communications, 2020, 11, 125.	12.8	33
6	Composite super-moir \tilde{A} lattices in double-aligned graphene heterostructures. Science Advances, 2019, 5, eaay 8897.	10.3	74
7	Exfoliation of single layer BiTel flakes. 2D Materials, 2018, 5, 031013.	4.4	34
8	Gate-Defined Quantum Confinement in InSe-Based van der Waals Heterostructures. Nano Letters, 2018, 18, 3950-3955.	9.1	40
9	Coexistence of classical snake states and Aharonov-Bohm oscillations along graphene <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:mi>p</mml:mi><mml:mtext>â^²<td>l:nstext><</td><td>mrabmi>n</td></mml:mtext></mml:mrow></mml:math>	l:n ste xt><	mr ab mi>n
10	Signatures of single quantum dots in graphene nanoribbons within the quantum Hall regime. Nanoscale, 2016, 8, 11480-11486.	5.6	10
11	Gate-controlled conductance enhancement from quantum Hall channels along graphene p–n junctions. Nanoscale, 2016, 8, 19910-19916.	5.6	10
12	Scalable Tight-Binding Model for Graphene. Physical Review Letters, 2015, 114, 036601.	7.8	74
13	Snake trajectories in ultraclean graphene p–n junctions. Nature Communications, 2015, 6, 6470.	12.8	93
14	Characterization of SiO2/SiNx gate insulators for graphene based nanoelectromechanical systems. Applied Physics Letters, 2014, 105, 123114.	3.3	3
15	Emergence of bound states in ballistic magnetotransport of graphene antidots. Physical Review B, 2014, 90, .	3.2	11
16	Fabrication of ballistic suspended graphene with local-gating. Carbon, 2014, 79, 486-492.	10.3	21
17	Large scale nanopatterning of graphene. Nuclear Instruments & Methods in Physics Research B, 2012, 282, 130-133.	1.4	12